# JEM-F200 Scanning Transmission Electron Microscope

JEM-F200 is a state-of-art high-resolution and analytical Scanning Transmission Electron Microscope. It is a 200 kV S/TEM equipped with a Cold Field Emission Gun for high brightness and a narrow energy spread that allows atomic resolution imaging, and with a Silicon Drift Detectors (SDD) which enable high sensitivity and throughput for X-ray (chemical) analysis.

### **DETAILED SPECIFICATIONS**

Accelerating Voltage: 200 kV
Alignment: 80 kV and 200 kV
Pole-Piece: High-Resolution

Gun: Cold-FEG

Quad lens condenser system to independently control intensity and convergence angle

TEM Resolution: 0.1 nm
STEM Resolution: 0.16 nm
EDS Detectors: 1 x 100 mm2

Camera: Gatan Rio Camera (Image: 16 MP, 9 μm pixel, optimal for 30 – 200 kV operation)

Holders: Standard Single-Tilt, Be Analytical Double-Tilt

### **USES/APPLICATIONS**

The F200 is capable of high sensitivity and resolution materials analysis.

#### **Authorized Materials**

Summary of material constraints

Lab members wishing to introduce new materials into this system must first obtain authorization from staff. New material requests must be initiated by submitting a request to: tem analysis.dsmn@unive.it

# **PROHIBITED Materials**

- 1. Any sample that will outgas under vacuum (check with staff if uncertain). This includes but is not limited to samples containing elemental sulphur or phosphorus
- 2. Samples containing any degree of moisture, including soft plastic or hydrogels
- 3. Geological samples
- 4. Biological samples
- 5. Magnetic materials of any type
- 6. No outside or specialized custom sample holders without specific authorization and consultation with staff.

# **Authorized Substrates & Thin Films**

• Polymer films: All photo/e-beam resists, conditional on them being fully baked/cured based on manufacturer's instructions.

•	CNTs, graphene	
•	Silicon	
•	III-V's	
•	ZnSe	
•	Ag	
•	Al	
•	Al2O3	
•	Au	
•	Bi2Te3	
•	Cr	
•	Cu	

•	HfO2
•	ITO
•	Nb
•	Ni
•	Pd
•	Pt
•	SiNx
•	SiO2
•	Ti
•	TiO2
•	TiW
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## NOTE:

EuS Ge

1. If any other materials are present on your samples, CONTACT STAFF

# **LOCATION**

The Ca' Foscari University of Venice, Scientific Campus, Department of Molecular Sciences and Nanosystems, Via Torino 155, Eta Building, Ground Floor, room ViaToCap0L13, Venezia-Mestre (Italy).

Information at tem\_analysis.dsmn@unive.it